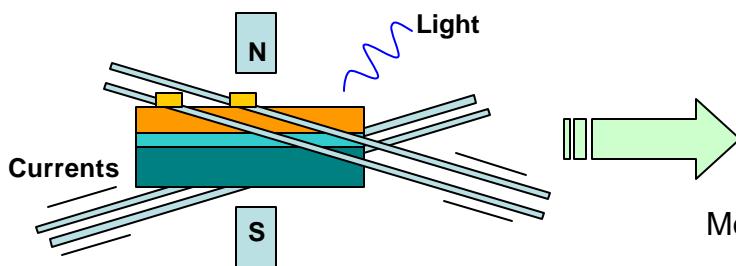


Spintronics and Diluted Magnetic Semiconductors

Spintronics, which combines the key advantages of microelectronics and micromagnetics, represents the New Frontier in Device Physics for Future Integrated Circuit Technology



: Needed :

Multi-Functional Magnetic Materials
with
High Spin Polarization

Most Carrier Spins preferring one direction over the other in applied magnetic field

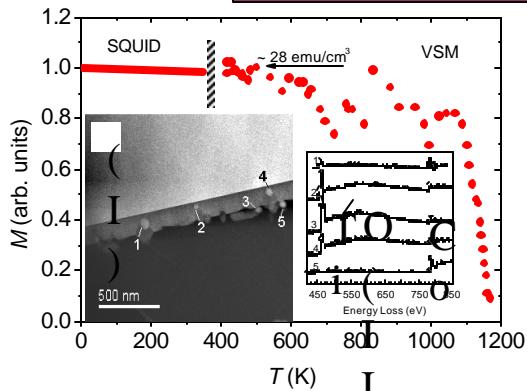
One Interesting Possibility : Diluted Magnetic Semiconductors Semiconductors with Dilute Concentration of Magnetic dopants

Prior Successes with CdMnSe, GaMnAs etc. (thin films) Furdyana, JAP 64,R29, 98, Ohno, Science 281, 951, 98

But No Ferromagnetism at or above room temperature

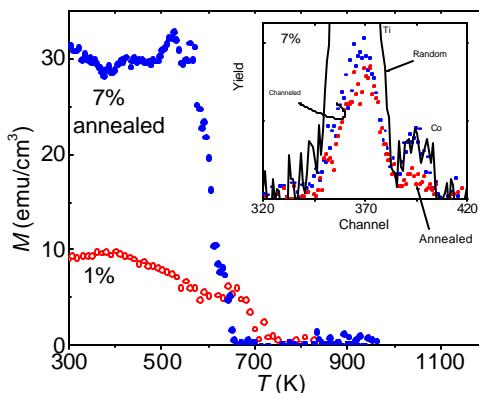
Recent Report of above room temp ferromagnetism in Anatase Co: TiO₂
Matsumoto et al Science 291, 854, 01

We used Pulsed Laser Deposition to grow anatase Co:TiO₂

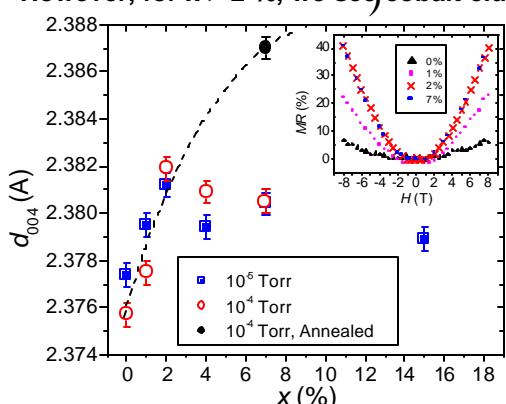


We see Magnetization At 300K and above.
However, for x > 2 %, we see cobalt clusters.

Cond-Mat
0203576



The magnetization data shows that when Co is substituted for Ti, T_C ~ 700 K. The inset shows the channeling behavior of 7% doped film after annealing.



NSF MRSEC
00-80008

The XRD and MR data suggest substitution of Co in TiO₂ for x < 2%. Even in x=7% Film, Co goes to substitutional site when annealed at high T.

CONCLUSION

Co substitutes in TiO₂ matrix either at low concentrations (x<2%) or after annealing at very high T (900 °C).

The Curie temperature of the true DMS is about 650 – 700 °C.

Shinde, Ogale, Das Sarma, Lofland, Kulkarni, Sharma, Higgins, Greene, Venkatesan, Simpson, Drew, Millis